



# **BC856AW - BC858CW**

# PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

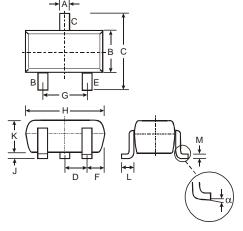
# **Features**

- Ideally Suited for Automated Insertion
- Complementary NPN Types Available (BC846W-BC848W)
- For Switching and AF Amplifier Applications
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

# **Mechanical Data**

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 5. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Pin Connections: See Diagram
- Marking Code: See Table Below & Diagram on Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)

Marking Code (Note 2)										
Type Marking Type Marking										
BC856AW	K3A	BC857CW	K3G							
BC856BW	K3B	BC858AW	K3J, K3A, K3V							
BC857AW	K3V, K3A	BC858BW	K3K, K3B, K3W							
BC857BW	K3W. K3B	BC858CW	K3L, K3G							



	SOT-323									
Dim	Min Max									
Α	0.25	0.40								
В	1.15	1.35								
С	2.00	2.20								
D	0.65 N	ominal								
Е	0.30 0.40									
G	1.20	1.40								
Н	1.80	2.20								
J	0.0 0.10									
K	0.90	1.00								
L	0.25 0.40									
М	0.10	0.18								
α	0° 8°									
All Dimensions in mm										

# **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Collector-Base Voltage	BC856		-80	
	BC857	$V_{CBO}$	-50	V
	BC858		-30	
Collector-Emitter Voltage	BC856		-65	
	BC857	$V_{\sf CEO}$	-45	V
	BC858		-30	
Emitter-Base Voltage		$V_{EBO}$	-5.0	V
Collector Current		Ic	-100	mA
Peak Collector Current		I <sub>CM</sub>	-200	mA
Peak Emitter Current		I <sub>EM</sub>	-200	mA
Power Dissipation (Note 1)		$P_d$	200	mW
Thermal Resistance, Junction to Ambient (No	te 1)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range		T <sub>j</sub> , T <sub>STG</sub>	-65 to +150	°C

Notes:

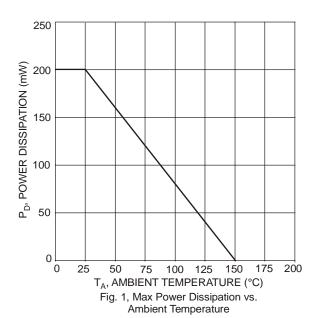
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- Current gain subgroup "C" is not available for BC856W.
- 3. No purposefully added lead.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- 5. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

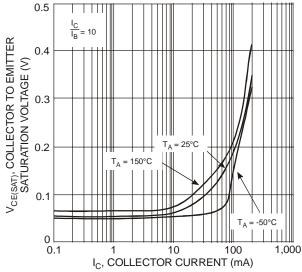


# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

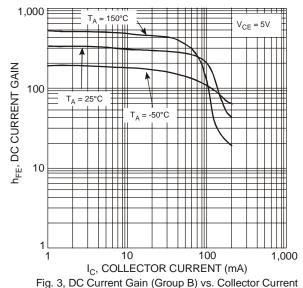
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage (Note 6)	BC856 BC857 BC858	V <sub>(BR)CBO</sub>	-80 -50 -30	-		V	$I_C = 10 \mu A, I_B = 0$
Collector-Emitter Breakdown Voltage (Note 6)	BC856 BC857 BC858	V <sub>(BR)CEO</sub>	-65 -45 -30	1	1 1 1	V	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage (Note 6)		$V_{(BR)EBO}$	-5	_	_	V	$I_E = 1\mu A, I_C = 0$
DC Current Gain (Note 6) Current Gain Group	A B C	h <sub>FE</sub>	125 220 420	180 290 520	250 475 800	_	V <sub>CE</sub> = -5.0V, I <sub>C</sub> = -2.0mA
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(SAT)</sub>	_	-75 -250	-300 -650	mV	$I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$ $I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$	
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(SAT)</sub>	_	-700 -850	-950	mV	$I_C = -10$ mA, $I_B = -0.5$ mA $I_C = -100$ mA, $I_B = -5.0$ mA	
Base-Emitter Voltage (Note 6)	V <sub>BE(ON)</sub>	-600 —	-650 —	-750 -820	mV	$V_{CE} = -5.0V$ , $I_{C} = -2.0$ mA $V_{CE} = -5.0V$ , $I_{C} = -10$ mA	
Collector-Cutoff Current (Note 6)		I <sub>CBO</sub>	_	1 1	-15 -4.0	nΑ μΑ	V <sub>CB</sub> = -30V V <sub>CB</sub> = -30V, T <sub>A</sub> = 150°C
Gain Bandwidth Product			100	200	l	MHz	$V_{CE} = -5.0V, I_{C} = -10mA,$ f = 100MHz
Collector-Base Capacitance	•	C <sub>CBO</sub>	_	3	4.5	pF	V <sub>CB</sub> = -10V, f = 1.0MHz
Noise Figure		NF		_	10	dB	$V_{CE}$ = -5.0V, $I_C$ = 200 $\mu$ A, $R_S$ = 2k $\Omega$ , $f$ = 1kHz, $\Delta f$ = 200Hz

Notes: 6. Short duration pulse test used to minimize self-heating effect.









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Fig. 4, Gain Bandwidth Product vs. Collector Current

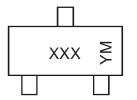
Device	Packaging	Shipping				
BC85xxW-7-F	SOT-323	3000/Tape & Reel				

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

(Note 5 & 7)

# **Marking Information**

**Ordering Information** 



XXX = Product Type Marking Code (See Page 1), e.g. K3A = BC856AW

YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

1,000

Date Code Key

Date Code Ney															
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	М	N	Р	R	S	Т	U	V	W	Χ	Υ	Z
Month	Jan	Fel	b l	Mar	Apr	May	Ju	n	Jul	Aug	Sep	Oc	t I	Nov	Dec
Code	1	2		3	4	5	6	;	7	8	9	0		N	D

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